

Features

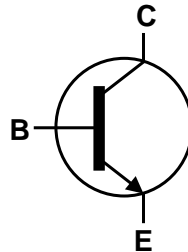
- $BV_{CE0} > 160V$
- Ideal for Low Power Amplification and Switching
- Complementary PNP Type Available (MMBT5401)
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

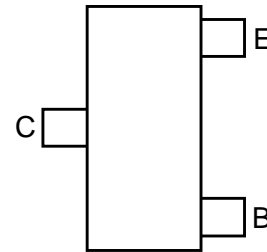
- Case: SOT-23
- Case Material: Molded Plastic, "Green" molding compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish-Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.008 grams (approximate)



Top View



Device Symbol



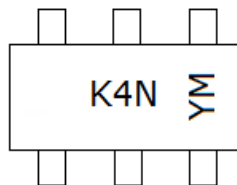
Top View Pin-Out

Ordering Information (Note 4)

| Part Number | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|--------------|------------|---------|--------------------|-----------------|-------------------|
| MMBT5551-7-F | AEC-Q101 | K4N | 7 | 8 | 3,000 |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



K4N = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: B = 2014)
 M = Month (ex: 9 = September)

Date Code Key

| Year | 2010 | 2011 | 2012 | 2013 | 2014 | 2015 | 2016 | 2017 |
|------|------|------|------|------|------|------|------|------|
| Code | X | Y | Z | A | B | C | D | E |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |

Absolute Maximum Ratings (@T_A = +25°C unless otherwise specified)

| Characteristic | Symbol | Value | Unit |
|---|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | 180 | V |
| Collector-Emitter Voltage | V _{CEO} | 160 | V |
| Emitter-Base Voltage | V _{EBO} | 6.0 | V |
| Collector Current - Continuous (Note 1) | I _C | 600 | mA |

Thermal Characteristics (@T_A = +25°C unless otherwise specified)

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 5) | P _D | 300 | mW |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{θJA} | 417 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

ESD Ratings (Note 6)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | C |

- Notes:
- 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 - 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

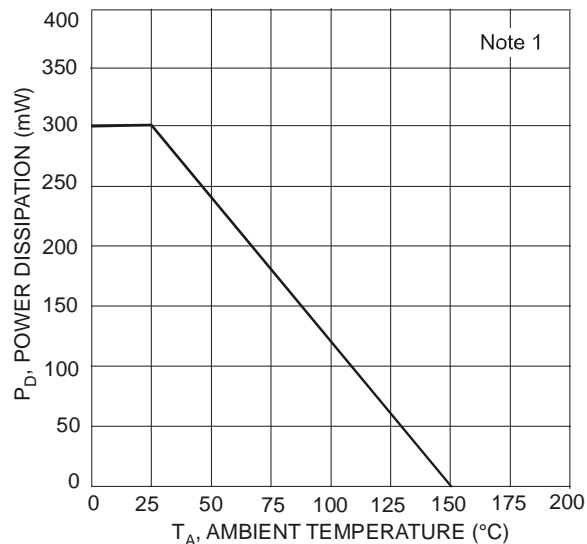


Fig. 1 Power Dissipation vs. Ambient Temperature

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

| Characteristic | Symbol | Min | Max | Unit | Test Condition |
|--------------------------------------|---------------|----------------|---------------|---------------------|--|
| OFF CHARACTERISTICS (Note 7) | | | | | |
| Collector-Base Breakdown Voltage | $V_{(BR)CBO}$ | 180 | — | V | $I_C = 100\mu\text{A}, I_E = 0$ |
| Collector-Emitter Breakdown Voltage | $V_{(BR)CEO}$ | 160 | — | V | $I_C = 1.0\text{mA}, I_B = 0$ |
| Emitter-Base Breakdown Voltage | $V_{(BR)EBO}$ | 6.0 | — | V | $I_E = 10\mu\text{A}, I_C = 0$ |
| Collector Cutoff Current | I_{CBO} | — | 50 | nA μA | $V_{CB} = 120\text{V}, I_E = 0$ $V_{CB} = 120\text{V}, I_E = 0, T_A = 100^\circ\text{C}$ |
| Emitter Cutoff Current | I_{EBO} | — | 50 | nA | $V_{EB} = 4.0\text{V}, I_C = 0$ |
| ON CHARACTERISTICS (Note 7) | | | | | |
| DC Current Gain | h_{FE} | 80 80 30 | — 250 — | — | $I_C = 1.0\text{mA}, V_{CE} = 5.0\text{V}$ $I_C = 10\text{mA}, V_{CE} = 5.0\text{V}$ $I_C = 50\text{mA}, V_{CE} = 5.0\text{V}$ |
| Collector-Emitter Saturation Voltage | $V_{CE(SAT)}$ | — | 0.15 0.20 | V | $I_C = 10\text{mA}, I_B = 1.0\text{mA}$ $I_C = 50\text{mA}, I_B = 5.0\text{mA}$ |
| Base-Emitter Saturation Voltage | $V_{BE(SAT)}$ | — | 1.0 | V | $I_C = 10\text{mA}, I_B = 1.0\text{mA}$ $I_C = 50\text{mA}, I_B = 5.0\text{mA}$ |
| SMALL SIGNAL CHARACTERISTICS | | | | | |
| Output Capacitance | C_{obo} | — | 6.0 | pF | $V_{CB} = 10\text{V}, f = 1.0\text{MHz}, I_E = 0$ |
| Small Signal Current Gain | h_{fe} | 50 | 250 | — | $V_{CE} = 10\text{V}, I_C = 1.0\text{mA}, f = 1.0\text{kHz}$ |
| Current Gain-Bandwidth Product | f_T | 100 | 300 | MHz | $V_{CE} = 10\text{V}, I_C = 10\text{mA}, f = 100\text{MHz}$ |
| Noise Figure | nF | — | 8.0 | dB | $V_{CE} = 5.0\text{V}, I_C = 200\mu\text{A}, R_S = 1.0\text{k}\Omega, f = 1.0\text{kHz}$ |

Notes: 7. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

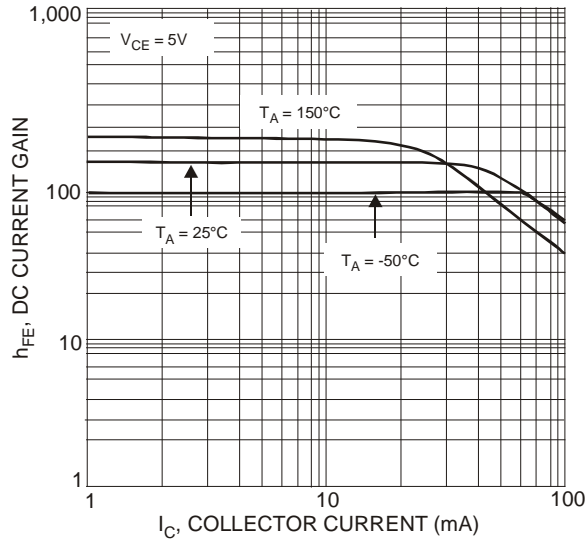


Fig. 2 Typical DC Current Gain vs. Collector Current

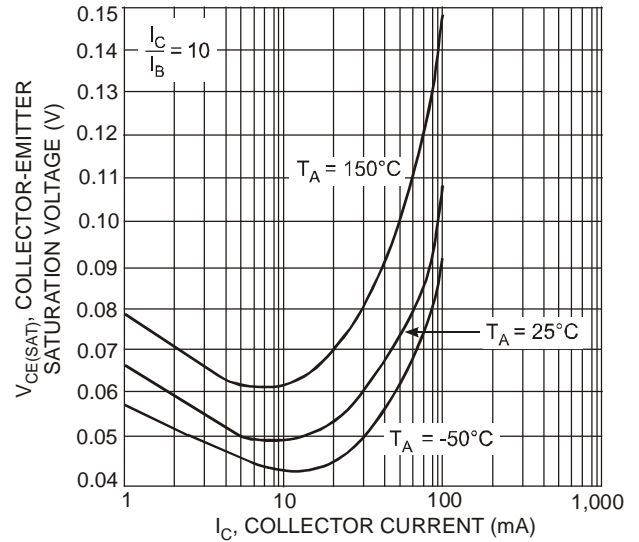


Fig. 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

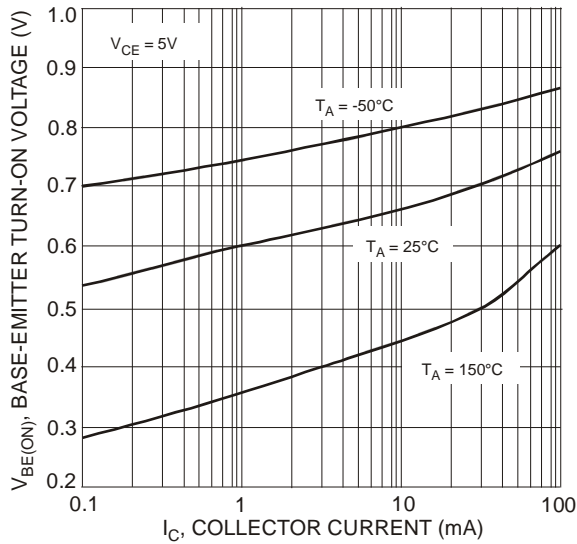


Fig. 4 Typical Base-Emitter Turn-On Voltage vs. Collector Current

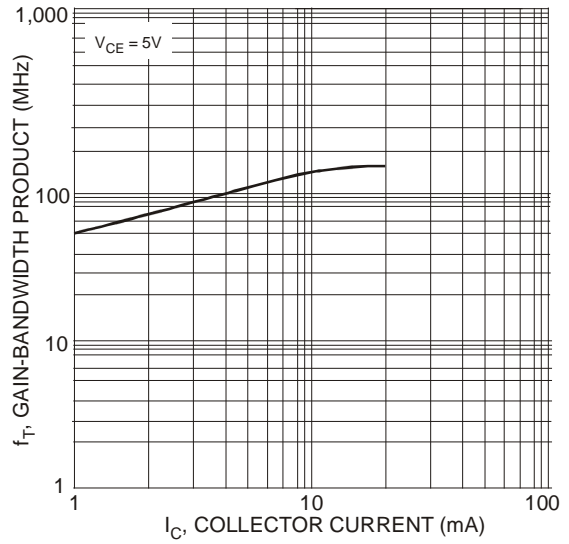
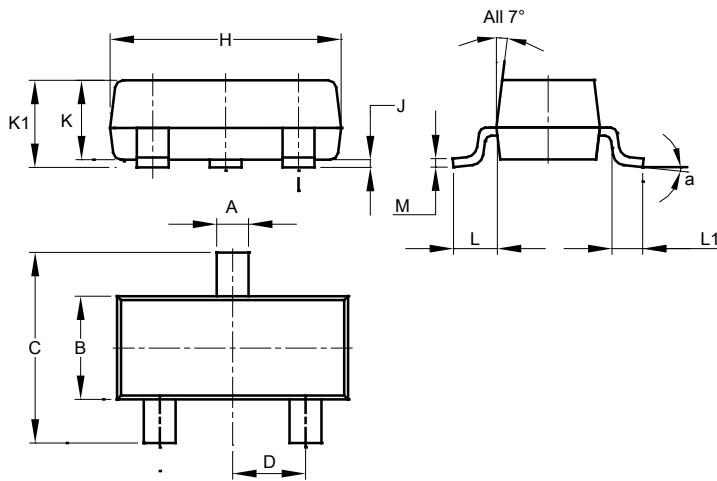


Fig. 5 Typical Gain-Bandwidth Product vs. Collector Current

Package Outline Dimensions

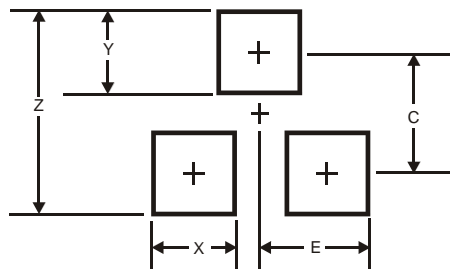
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



| SOT23 | | | |
|----------------------|-------|-------|-------|
| Dim | Min | Max | Typ |
| A | 0.37 | 0.51 | 0.40 |
| B | 1.20 | 1.40 | 1.30 |
| C | 2.30 | 2.50 | 2.40 |
| D | 0.89 | 1.03 | 0.915 |
| F | 0.45 | 0.60 | 0.535 |
| G | 1.78 | 2.05 | 1.83 |
| H | 2.80 | 3.00 | 2.90 |
| J | 0.013 | 0.10 | 0.05 |
| K | 0.890 | 1.00 | 0.975 |
| K1 | 0.903 | 1.10 | 1.025 |
| L | 0.45 | 0.61 | 0.55 |
| L1 | 0.25 | 0.55 | 0.40 |
| M | 0.085 | 0.150 | 0.110 |
| a | 8° | | |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.9 |
| X | 0.8 |
| Y | 0.9 |
| C | 2.0 |
| E | 1.35 |

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